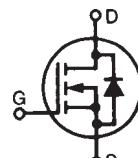


# HiPerFET™ Power MOSFETs Q-Class

**IXFN 44N50Q**  
**IXFN 48N50Q**

N-Channel Enhancement Mode  
Avalanche Rated, Low Q<sub>g</sub>, High dv/dt



### Maximum Ratings

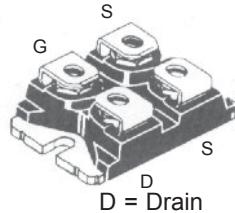
| Symbol            | Test Conditions                                                                                                                        | 44N50       | 48N50 | A         |
|-------------------|----------------------------------------------------------------------------------------------------------------------------------------|-------------|-------|-----------|
| V <sub>DSS</sub>  | T <sub>J</sub> = 25°C to 150°C                                                                                                         | 500         |       | V         |
| V <sub>DGR</sub>  | T <sub>J</sub> = 25°C to 150°C; R <sub>GS</sub> = 1 MΩ                                                                                 | 500         |       | V         |
| V <sub>GS</sub>   | Continuous                                                                                                                             | ±20         |       | V         |
| V <sub>GSM</sub>  | Transient                                                                                                                              | ±30         |       | V         |
| I <sub>D25</sub>  | T <sub>C</sub> = 25°C                                                                                                                  | 44N50       | 44    | A         |
|                   |                                                                                                                                        | 48N50       | 48    | A         |
| I <sub>DM</sub>   | T <sub>C</sub> = 25°C, pulse width limited by T <sub>JM</sub>                                                                          | 44N50       | 176   | A         |
|                   |                                                                                                                                        | 48N50       | 192   | A         |
| I <sub>AR</sub>   | T <sub>C</sub> = 25°C                                                                                                                  |             | 48    | A         |
| E <sub>AR</sub>   | T <sub>C</sub> = 25°C                                                                                                                  |             | 60    | mJ        |
| E <sub>AS</sub>   |                                                                                                                                        |             | 2.5   | mJ        |
| dv/dt             | I <sub>S</sub> ≤ I <sub>DM</sub> , di/dt ≤ 100 A/μs, V <sub>DD</sub> ≤ V <sub>DSS</sub> , T <sub>J</sub> ≤ 150°C, R <sub>G</sub> = 2 Ω |             | 15    | V/ns      |
| P <sub>D</sub>    | T <sub>C</sub> = 25°C                                                                                                                  | 500         |       | W         |
| T <sub>J</sub>    |                                                                                                                                        | -55 to +150 |       | °C        |
| T <sub>JM</sub>   |                                                                                                                                        | 150         |       | °C        |
| T <sub>stg</sub>  |                                                                                                                                        | -55 to +150 |       | °C        |
| V <sub>ISOL</sub> | 50/60 Hz, RMS t = 1 min                                                                                                                | 2500        |       | V~        |
|                   | I <sub>ISOL</sub> ≤ 1 mA t = 1 s                                                                                                       | 3000        |       | V~        |
| M <sub>d</sub>    | Mounting torque                                                                                                                        | 1.5/13      |       | Nm/lb.in. |
|                   | Terminal connection torque                                                                                                             | 1.5/13      |       | Nm/lb.in. |
| Weight            |                                                                                                                                        | 30          |       | g         |

| Symbol              | Test Conditions                                               | Characteristic Values                               |      |      |
|---------------------|---------------------------------------------------------------|-----------------------------------------------------|------|------|
|                     |                                                               | (T <sub>J</sub> = 25°C, unless otherwise specified) | min. | typ. |
| V <sub>DSS</sub>    | V <sub>GS</sub> = 0 V, I <sub>D</sub> = 1 mA                  | 500                                                 |      | V    |
| V <sub>GS(th)</sub> | V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 4 mA     | 2.0                                                 |      | V    |
| I <sub>GSS</sub>    | V <sub>GS</sub> = ±20 V <sub>DC</sub> , V <sub>DS</sub> = 0   |                                                     | ±100 | nA   |
| I <sub>DSS</sub>    | V <sub>DS</sub> = V <sub>DSS</sub><br>V <sub>GS</sub> = 0 V   | T <sub>J</sub> = 25°C<br>T <sub>J</sub> = 125°C     | 100  | μA   |
| R <sub>DS(on)</sub> | V <sub>GS</sub> = 10 V, I <sub>D</sub> = 0.5 I <sub>D25</sub> | 44N50<br>48N50                                      | 120  | Ω    |
|                     | Pulse test, t ≤ 300 μs, duty cycle d ≤ 2 %                    |                                                     | 100  | Ω    |

| V <sub>DSS</sub> | I <sub>D25</sub> | R <sub>DS(on)</sub> |
|------------------|------------------|---------------------|
| 500 V            | 44 A             | 120 mΩ              |
| 500 V            | 48 A             | 100 mΩ              |

t<sub>rr</sub> ≤ 250 ns

miniBLOC, SOT-227 B (IXFN)  
E153432



G = Gate  
S = Source

Either Source terminal at miniBLOC can be used as Main or Kelvin Source

### Features

- IXYS advanced low Q<sub>g</sub> process
- Low gate charge and capacitances
  - easier to drive
  - faster switching
- Unclamped Inductive Switching (UIS) rated
- Low R<sub>DS(on)</sub>
- Fast intrinsic diode
- International standard package
- miniBLOC with Aluminium nitride isolation for low thermal resistance
- Low terminal inductance (<10 nH) and stray capacitance to heatsink (<35pf)
- Molding epoxies meet UL 94 V-0 flammability classification

### Applications

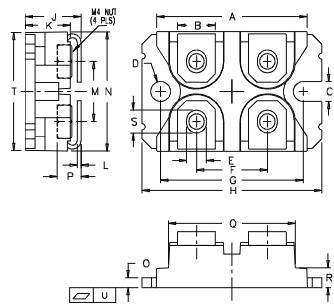
- DC-DC converters
- Battery chargers
- Switched-mode and resonant-mode power supplies
- DC choppers
- Temperature and lighting controls

### Advantages

- Easy to mount
- Space savings
- High power density

| Symbol                                        | Test Conditions                                                                                              | Characteristic Values                                    |      |      |      |
|-----------------------------------------------|--------------------------------------------------------------------------------------------------------------|----------------------------------------------------------|------|------|------|
|                                               |                                                                                                              | ( $T_J = 25^\circ\text{C}$ , unless otherwise specified) | min. | typ. | max. |
| $g_{fs}$                                      | $V_{DS} = 20\text{ V}; I_D = 0.5 \cdot I_{D25}$ , pulse test                                                 | 30                                                       | 42   | S    |      |
| $C_{iss}$<br>$C_{oss}$<br>$C_{rss}$           | $V_{GS} = 0\text{ V}, V_{DS} = 25\text{ V}, f = 1\text{ MHz}$                                                | 7000                                                     | pF   |      |      |
|                                               |                                                                                                              | 960                                                      | pF   |      |      |
|                                               |                                                                                                              | 230                                                      | pF   |      |      |
| $t_{d(on)}$<br>$t_r$<br>$t_{d(off)}$<br>$t_f$ | $V_{GS} = 10\text{ V}, V_{DS} = 0.5 \cdot V_{DSS}, I_D = 0.5 \cdot I_{D25}$<br>$R_G = 4.7\Omega$ (External), | 33                                                       | ns   |      |      |
|                                               |                                                                                                              | 22                                                       | ns   |      |      |
|                                               |                                                                                                              | 75                                                       | ns   |      |      |
|                                               |                                                                                                              | 10                                                       | ns   |      |      |
| $Q_{g(on)}$<br>$Q_{gs}$<br>$Q_{gd}$           | $V_{GS} = 10\text{ V}, V_{DS} = 0.5 \cdot V_{DSS}, I_D = 0.5 \cdot I_{D25}$                                  | 190                                                      | nC   |      |      |
|                                               |                                                                                                              | 40                                                       | nC   |      |      |
|                                               |                                                                                                              | 86                                                       | nC   |      |      |
| $R_{thJC}$                                    |                                                                                                              |                                                          | 0.26 | K/W  |      |
| $R_{thCK}$                                    |                                                                                                              |                                                          | 0.05 | K/W  |      |

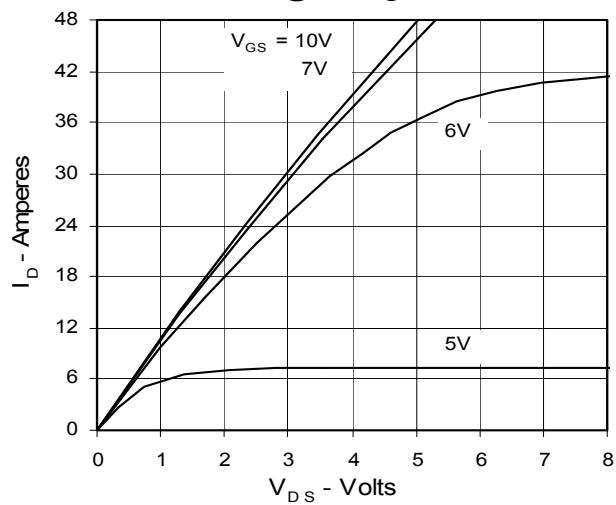
| Symbol                           | Test Conditions                                                                                            | Characteristic Values                                    |      |               |      |
|----------------------------------|------------------------------------------------------------------------------------------------------------|----------------------------------------------------------|------|---------------|------|
|                                  |                                                                                                            | ( $T_J = 25^\circ\text{C}$ , unless otherwise specified) | min. | typ.          | max. |
| $I_s$                            | $V_{GS} = 0\text{ V}$                                                                                      |                                                          | 48   | A             |      |
| $I_{SM}$                         | Repetitive; pulse width limited by $T_{JM}$                                                                |                                                          | 192  | A             |      |
| $V_{SD}$                         | $I_F = I_s, V_{GS} = 0\text{ V},$<br>Pulse test, $t \leq 300\text{ }\mu\text{s}$ , duty cycle $d \leq 2\%$ |                                                          | 1.5  | V             |      |
| $t_{rr}$<br>$Q_{RM}$<br>$I_{RM}$ | $I_F = 25\text{ A}, -di/dt = 100\text{ A}/\mu\text{s}, V_R = 100\text{ V}$                                 | 1.0                                                      | 250  | ns            |      |
|                                  |                                                                                                            | 10                                                       |      | $\mu\text{C}$ |      |
|                                  |                                                                                                            |                                                          |      | A             |      |

**miniBLOCS, SOT-227 B**


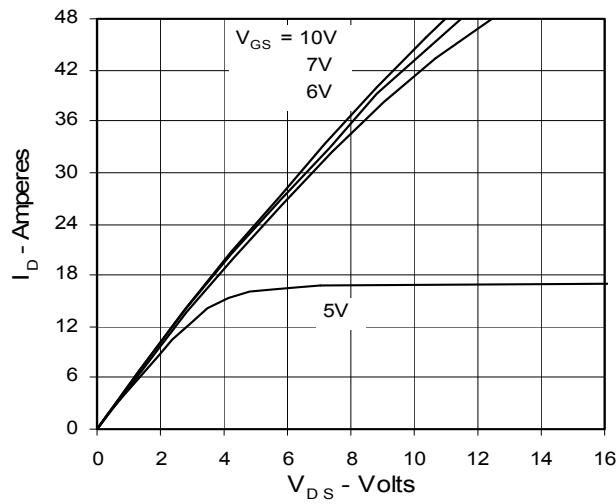
M4 screws (4x) supplied

| Dim. | Millimeter<br>Min. | Millimeter<br>Max. | Inches<br>Min. | Inches<br>Max. |
|------|--------------------|--------------------|----------------|----------------|
| A    | 31.50              | 31.88              | 1.240          | 1.255          |
| B    | 7.80               | 8.20               | 0.307          | 0.323          |
| C    | 4.09               | 4.29               | 0.161          | 0.169          |
| D    | 4.09               | 4.29               | 0.161          | 0.169          |
| E    | 4.09               | 4.29               | 0.161          | 0.169          |
| F    | 14.91              | 15.11              | 0.587          | 0.595          |
| G    | 30.12              | 30.30              | 1.186          | 1.193          |
| H    | 38.00              | 38.23              | 1.496          | 1.505          |
| J    | 11.68              | 12.22              | 0.460          | 0.481          |
| K    | 8.92               | 9.60               | 0.351          | 0.378          |
| L    | 0.76               | 0.84               | 0.030          | 0.033          |
| M    | 12.60              | 12.85              | 0.496          | 0.506          |
| N    | 25.15              | 25.42              | 0.990          | 1.001          |
| O    | 1.98               | 2.13               | 0.078          | 0.084          |
| P    | 4.95               | 5.97               | 0.195          | 0.235          |
| Q    | 26.54              | 26.90              | 1.045          | 1.059          |
| R    | 3.94               | 4.42               | 0.155          | 0.174          |
| S    | 4.72               | 4.85               | 0.186          | 0.191          |
| T    | 24.59              | 25.07              | 0.968          | 0.987          |
| U    | -0.05              | 0.1                | -0.002         | 0.004          |

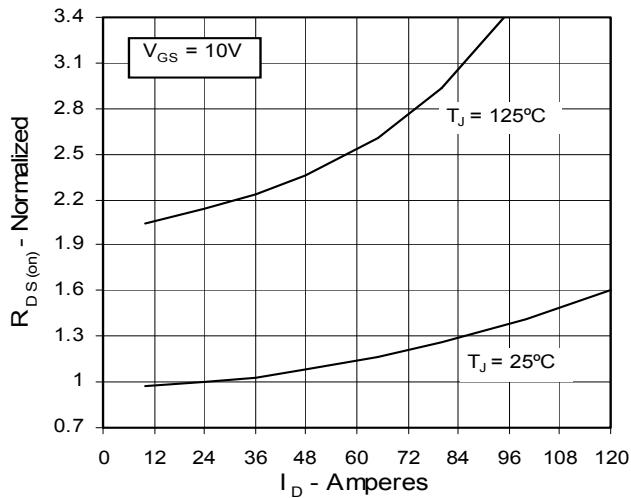
**Fig. 1. Output Characteristics  
@ 25 Deg. C**



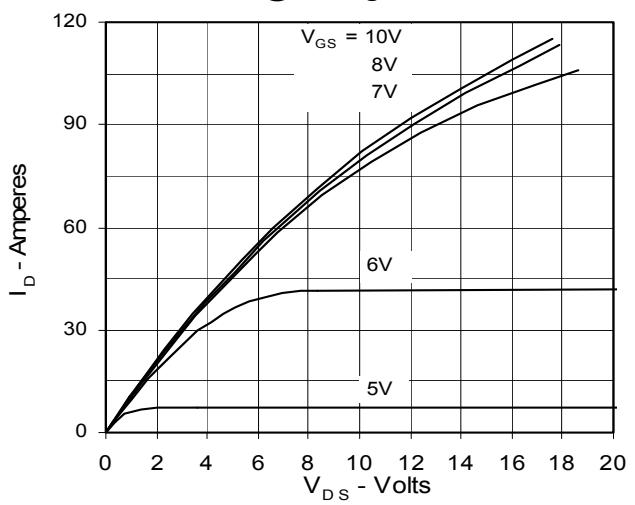
**Fig. 3. Output Characteristics  
@ 125 Deg. C**



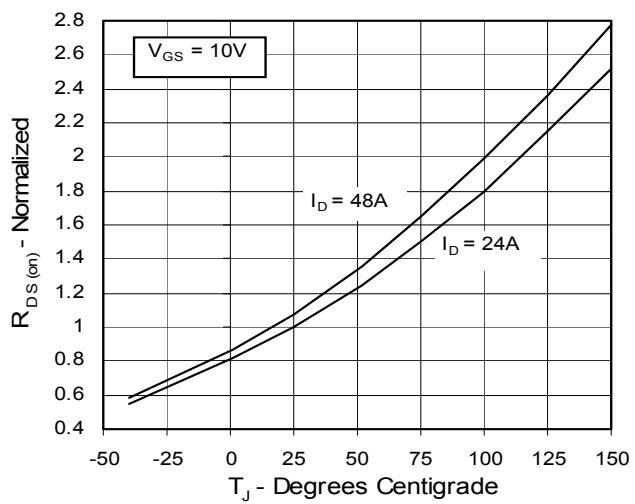
**Fig. 5.  $R_{DS(on)}$  Normalized to  $I_{D25}$  Value vs.  $I_D$**



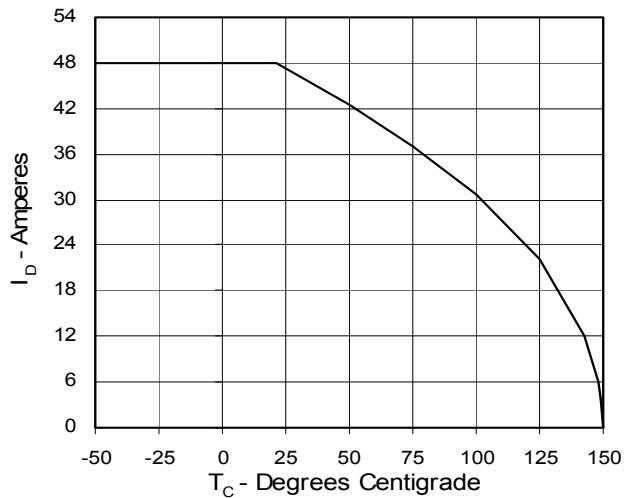
**Fig. 2. Extended Output Characteristics  
@ 25 deg. C**

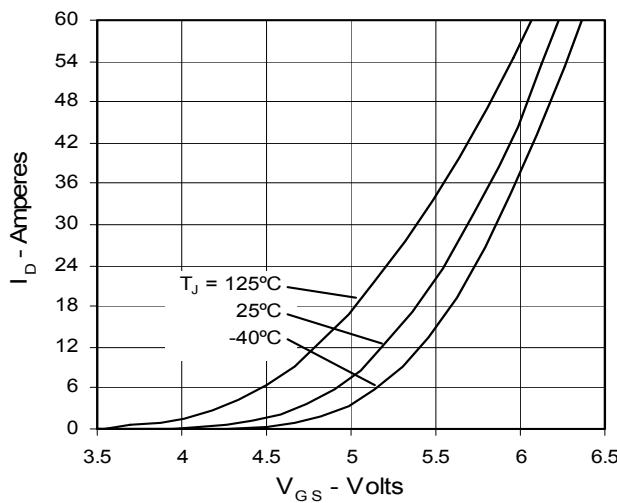
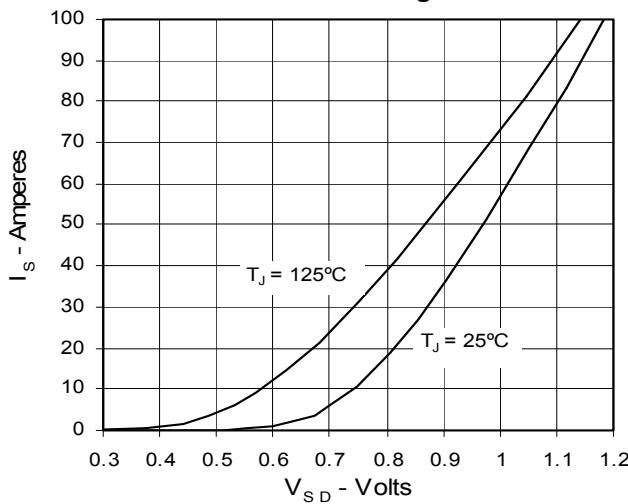
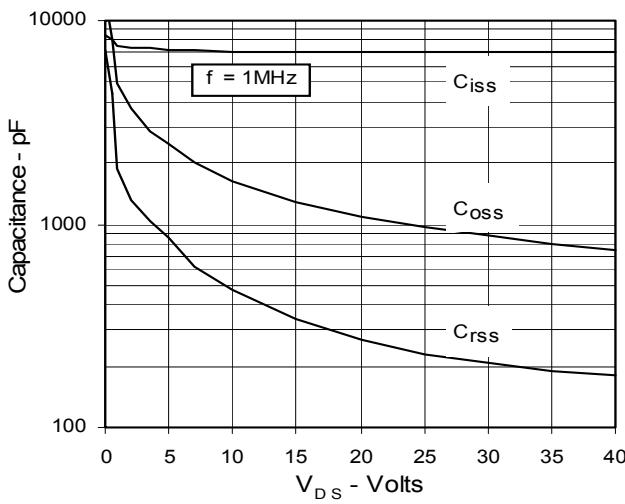
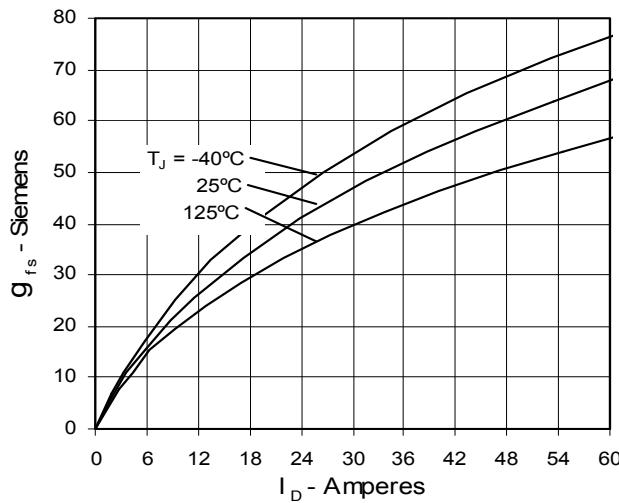
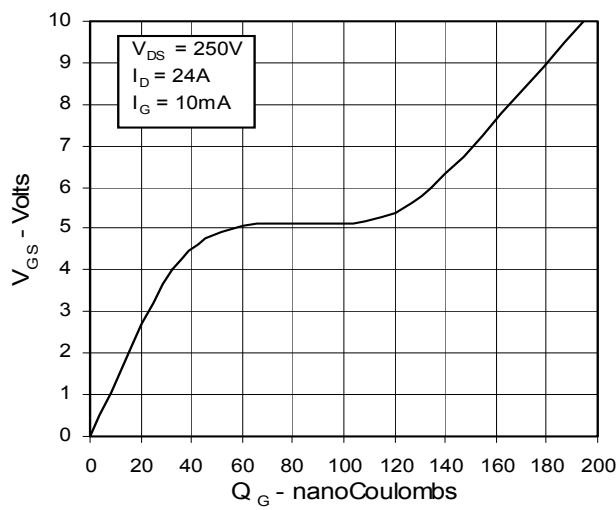
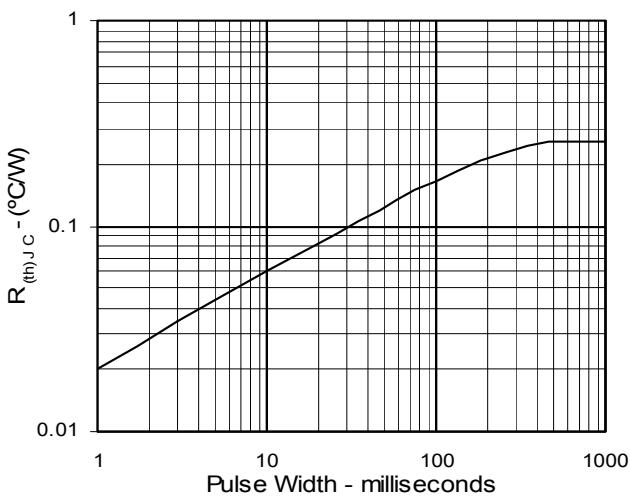


**Fig. 4.  $R_{DS(on)}$  Normalized to  $I_{D25}$  Value vs.  
Junction Temperature**



**Fig. 6. Drain Current vs. Case  
Temperature**



**Fig. 7. Input Admittance**

**Fig. 9. Source Current vs. Source-To-Drain Voltage**

**Fig. 11. Capacitance**

**Fig. 8. Transconductance**

**Fig. 10. Gate Charge**

**Fig. 12. Maximum Transient Thermal Resistance**


IXYS reserves the right to change limits, test conditions, and dimensions.

IXYS MOSFETs and IGBTs are covered by one or more of the following U.S. patents:

 4,835,592 4,881,106 5,017,508 5,049,961 5,187,117 5,486,715 6,306,728B1 6,259,123B1 6,306,728B1  
 4,850,072 4,931,844 5,034,796 5,063,307 5,237,481 5,381,025 6,404,065B1 6,162,665 6,534,343



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